## NSN 5961-01-532-3553

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-532-3553 **Inclosure Material:** Plastic **Overall Length:** Between 0.140 inches and 0.152 inches **Overall Height:** Between 0.037 inches and 0.053 inches **Overall Width:** Between 0.055 inches and 0.071 inches **End Application:** Nsn: 4935-01-136-0233; shop equipment, guided missile system; ws: missile, patriot, **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 9.5 regulator voltage and 10.0 regulator voltage **Current Rating Per Characteristic:** 10.00 milliamperes collector current, dc **Power Rating Per Characteristic:** 500.0 milliwatts any acceptable megawatts **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure:** Demilitarization: No